

Over-voltage Protection Thyristor

SPXXX0SB

ROHS

Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

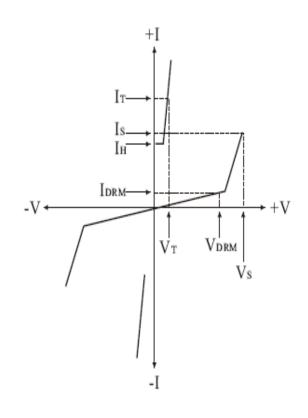


Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	er Definition				
C 0	Off-state Capacitance — typical capacitance				
	measured in off state				
di/dt	Rate of Rise of Current — maximum rated value				
	the acceptable rate of rise in current over time				
Is Switching Current — maximum current requir					
	switch to on state				
I DRM	Leakage Current — maximum peak off-state current				
	measured at VDRM				
\mathbf{I}_{H}	Holding Current — minimum current required to				
	maintain on state				
\mathbf{I} PP	Peak Pulse Current — maximum rated peak impulse				
	current				
\mathbf{I}^{\intercal}	On-state Current — maximum rated continuous				
	on-state current				
I TSM	Peak One-cycle Surge Current — maximum rated				
	one-cycle AC current				
V S	Switching Voltage — maximum voltage prior to				
	switching to on state				
V DRM	Peak Off-state Voltage — maximum voltage that can				
	be applied while maintaining off state				
V F	On-state Forward Voltage — maximum forward				
	voltage measured at rated on-state current				
V T	On-state Voltage — maximum voltage measured at				
	rated on-state current				





Over-voltage Protection Thyristor **SPXXX0SB ROHS** ElectricalCharacteristics Part VDRM Vs Vт Is Co IDRM Ιτ ΙH Number* Volts Volts рF Volts μ Amps mAmps mAmps Amps SP0080SB 2.2 SP0300SB 2.2 SP0640SB 2. 2 2. 2 SP0720SB SP0900SB 2.2 SP1100SB 2. 2 SP1300SB 2.2 SP1500SB 2. 2 2.2 SP1800SB SP2000SB 2. 2 SP2300SB 2.2 SP2600SB 2. 2 SP3100SB 2.2 2.2 SP3500SB SP4000SB 2. 2 SP4500SB 2.2

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

• Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Ratings

SP5000SB

Series	Ipp 2x10 µs	Ipp 8x20 µs	Ірр 10х160 µs	Ipp 10х560 µs	Ірр 10х1000 µs	Itsm 60 Hz	di/dt
В	Amps 250	Amps 250	Amps 150	Amps 100	Amps 80	Amps 30	Amps/µs

2. 2

Thermal Considerations

Package DO-214AA/SMB	Symbol	Parameter	Value	Unit
	ТЈ	Operating Junction Temperature	-40 to +150	$^{\circ}\!\mathbb{C}$
	Ts	Storage Temperature Range	-40 to +150	$^{\circ}\!\mathbb{C}$
	R ө да	Junction to Ambient on printed circuit	90	°C/W

^{*} For surge ratings, see table below.

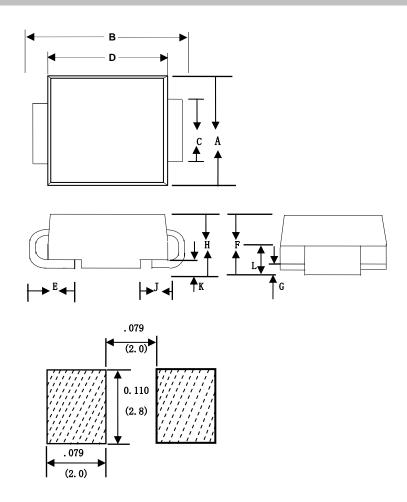


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Dimensions



Dimension	In	ches	Millimeters		
	MIN	MAX	MIN	MAX	
A	0. 134	0. 155	3. 40	3. 94	
В	0. 205	0. 22	5. 21	5. 59	
С	0. 075	0. 083	1. 90	2. 11	
D	0. 166	0. 185	4. 22	4. 70	
Е	0. 036	0.056	0. 91	1. 42	
F	0. 073	0. 087	1.85	2. 2	
G	0.002	0.008	0. 05	0. 20	
Н	0. 077	0.094	1. 95	2. 40	
J	0.043	0. 053	1. 09	1. 35	
K	0.008	0.014	0. 20	0. 35	
L	0. 039	0. 049	0. 99	1. 24	

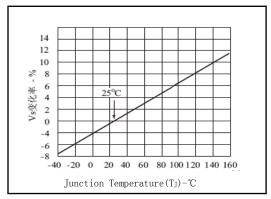
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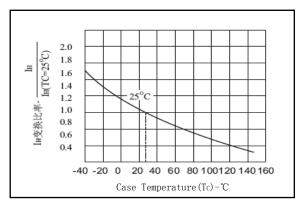
Over-voltage Protection Thyristor Summary of Packing Options Package Type Description Packing Industry Quantity Standard DO-214AA Embossed Carrier Reel Pack 2500 PCS EIA-481-1

SPXXX0SB

Thermal Derating Curves



Normalized VS Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature

